INTEGRATED CIRCUITS

DATA SHEET

74LVT640

3.3V Octal transceiver with direction pin; inverting (3-State)

Product specification
Supersedes data of 1996 Oct 01
IC23 Data Handbook





3.3V Octal transceiver with direction pin; inverting (3-State)

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FEATURES

- Octal bidirectional bus interface
- 3-State buffers
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power-up 3-State
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

DESCRIPTION

The LVT640 is a high-performance BiCMOS product designed for V_{CC} operation at 3.3V.

This device is an octal transceiver featuring inverting 3-State bus compatible outputs in both send and receive directions. The control function implementation minimizes external timing requirements. The device features an Output Enable ($\overline{\text{OE}}$) input for easy cascading and a Direction (DIR) input for direction control.

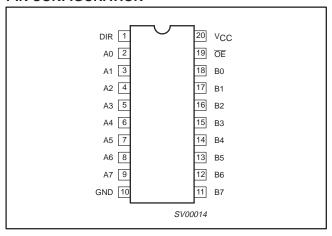
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t _{PLH} Propagation delay t _{PHL} An to Bn or Bn to An		$C_L = 50pF;$ $V_{CC} = 3.3V$	2.3 2.4	ns
C _{IN}	Input capacitance DIR, OE	V _I = 0V or 3.0V	4	pF
C _{I/O}	I/O pin capacitance	Outputs disabled; V _{I/O} = 0V or 3.0V	7	pF
I _{CCZ}	Total supply current	Outputs disabled; V _{CC} = 3.6V	0.13	mA

ORDERING INFORMATION

ONDERNING INI ORMIATION				
PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
20-Pin Plastic SO	–40°C to +85°C	74LVT640 D	74LVT640 D	SOT163-1
20-Pin Plastic SSOP	-40°C to +85°C	74LVT640 DB	74LVT640 DB	SOT339-1
20-Pin Plastic TSSOP	-40°C to +85°C	74LVT640 PW	74LVT640PW DH	SOT360-1

PIN CONFIGURATION



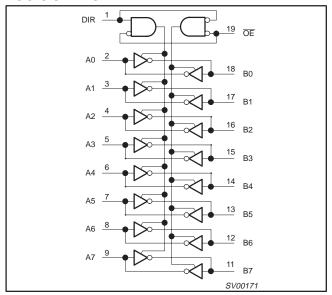
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	DIR	Direction control input
2, 3, 4, 5, 6, 7, 8, 9	A0 – A7	Data inputs/outputs (A side)
18, 17, 16, 15, 14, 13, 12, 11	B0 – B7	Data inputs/outputs (B side)
19	ŌĒ	Output enable input (active–Low)
10	GND	Ground (0V)
20	V _{CC}	Positive supply voltage

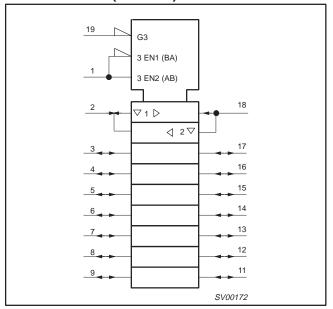
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LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

INP	JTS	INPUTS/OUTPUTS			
OE n	DIR	An	Bn		
L	L	Bn	Inputs		
L	Н	Inputs	Ān		
Н	Х	Z	Z		

H = High voltage level

L = Low voltage level

X = Don't care

Z = High impedance "Off" state

ABSOLUTE MAXIMUM RATINGS1,2

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT	
V _{CC}	DC supply voltage		-0.5 to +4.6	V	
I _{IK}	DC input diode current	V _I < 0	-50	mA	
VI	DC input voltage ³		-0.5 to +7.0	V	
I _{OK}	DC output diode current	V _O < 0	-50	mA	
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V	
	DC output ourroat	Output in Low state	128	A	
lout	DC output current	Output in High state	-64	mA	
T _{stg}	Storage temperature range		-65 to +150	°C	

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the
 device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to
 absolute-maximum-rated conditions for extended periods may affect device reliability.
- The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	ITS	UNIT
STWIBOL	TANAMETER	MIN	MAX	ONIT
V _{CC}	DC supply voltage	2.7	3.6	V
V _I	Input voltage	0	5.5	V
V _{IH}	High-level input voltage	2.0		V
V_{IL}	Input voltage		0.8	V
I _{OH}	High-level output current		-32	mA
la.	Low-level output current		32	mA
loL	Low-level output current; current duty cycle ≤ 50%; f ≥ 1kHz		64	ША
Δt/Δν	Input transition rise or fall rate; Outputs enabled		10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

DC ELECTRICAL CHARACTERISTICS

					LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS		Temp =	-40°C to -	-85°C	100 μA 1100 μA 1100 μA 1100 μA
				MIN	TYP ¹	MAX	1
V _{IK}	Input clamp voltage	$V_{CC} = 2.7V; I_{IK} = -18mA$		-0.9	-1.2	V	
		$V_{CC} = 2.7 \text{ to } 3.6 \text{V}; I_{OH} = -100 \mu\text{A}$		V _{CC} -0.2	V _{CC} -0.1		
V_{OH}	High-level output voltage	$V_{CC} = 2.7V; I_{OH} = -8mA$		2.4	2.5		V
		$V_{CC} = 3.0V; I_{OH} = -32mA$		2.0	2.2		
		$V_{CC} = 2.7V; I_{OL} = 100\mu A$			0.1	0.2	
		$V_{CC} = 2.7V; I_{OL} = 24mA$			0.3	0.5	
V_{OL}	Low-level output voltage	V _{CC} = 3.0V; I _{OL} = 16mA			0.25	0.4	V
		$V_{CC} = 3.0V; I_{OL} = 32mA$	CC = 3.0V; I _{OL} = 32mA			0.5	
		$V_{CC} = 3.0V; I_{OL} = 64mA$		0.4	0.55		
		$V_{CC} = 0 \text{ or } 3.6V; V_{I} = 5.5V$	Control pins		1	10	
II		$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND	Control pins		±0.1	±1	
	Input leakage current	V _{CC} = 3.6V; V _I = 5.5V			1		μΑ
		$V_{CC} = 3.6V; V_I = V_{CC}$	I/O Data pins ⁴	0.1 1	1]	
		$V_{CC} = 3.6V; V_I = 0$	1		-1	-5	
I _{OFF}	Output off current	$V_{CC} = 0V$; V_I or $V_O = 0$ to 4.5V			1	±100	μΑ
		$V_{CC} = 3V; V_{I} = 0.8V$		75	150		
I_{HOLD}	Bus Hold current A inputs NO TAG	$V_{CC} = 3V; V_{I} = 2.0V$		-75	-150		μΑ
	1	$V_{CC} = 0V \text{ to } 3.6V; V_{CC} = 3.6V$		±500			
I_{EX}	Current into an ouptut in the High state when V _O > V _{CC}	$V_O = 5.5V; V_{CC} = 3.0V$			60	125	μΑ
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \le 1.2V$; $V_O = 0.5V$ to V_{CC} ; $V_I = GNI$ $OE/\overline{OE} = Don't$ care	O or V _{CC} ;		15	±100	μА
I _{CCH}		$V_{CC} = 3.6V$; Outputs High, $V_I = GND$ or		0.13	0.19		
I _{CCL}	Quiescent supply current	$V_{CC} = 3.6V$; Outputs Low, $V_I = GND$ or $V_{CC} = 0.00$		3	12	mA	
I _{CCZ}		$V_{CC} = 3.6V$; Outputs Disabled; $V_I = GNI$		0.13	0.19		
ΔI_{CC}	Additional supply current per input pin ²	V_{CC} = 3V to 3.6V; One input at V_{CC} -0.6 Other inputs at V_{CC} or GND	V,		0.1	0.2	mA

- All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
 This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
 This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V a transition time of 100 μ sec is permitted. This parameter is valid for $T_{amb} = +25^{\circ}C$ only.

 4. Unused pins at V_{CC} or GND.
- 5. This is the bus hold overdrive current required to force the input to the opposite logic state.

3.3V Octal transceiver with direction pin; inverting (3-State)

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AC CHARACTERISTICS

GND = 0V; t_R = t_F = 2.5ns; C_L = 50pF; R_L = 500 Ω ; T_{amb} = -40°C to +85°C.

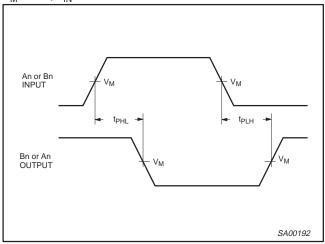
				LI	MITS		
SYMBOL	PARAMETER	WAVEFORM	V _{CC} = 3.3V +0.3V		V _{CC} = 2.7V	UNIT	
			MIN	TYP ¹	MAX	MAX	
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	NO TAG	1.0 1.0	2.3 2.4	3.7 3.3	4.5 3.1	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	NO TAG	1.1 1.5	3.5 3.6	5.3 5.3	6.9 6.2	ns
t _{PHZ}	Output disable time from High and Low Level	NO TAG	2.2 2.0	3.7 3.1	5.0 4.5	5.6 4.5	ns

NOTES:

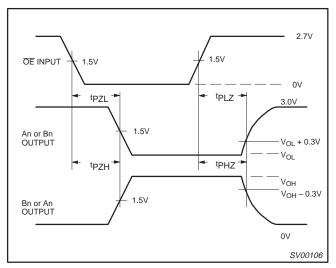
1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

AC WAVEFORMS

 $V_M = 1.5V$, $V_{IN} = GND$ to 2.7V



Waveform 1. Input (An or Bn) to Output (Bn or An) Propagation Delays



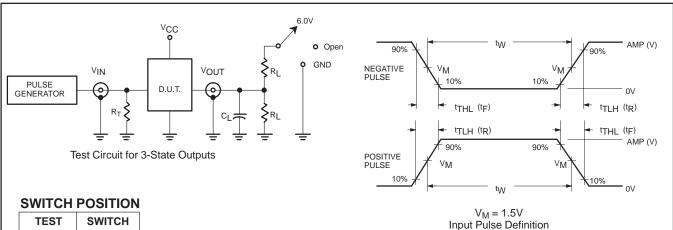
Waveform 2. 3-State Output Enable and Disable Times

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TEST CIRCUIT AND WAVEFORMS



TEST	SWITCH
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	6V
t _{PHZ} /t _{PZH}	GND

DEFINITIONS

 R_L = Load resistor; see AC CHARACTERISTICS for value.

 C_L = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

 $R_T = -$ Termination resistance should be equal to Z_{OUT} of pulse generators.

FAMILY	IN	PUT PULSE R	EQUIRE	MENTS	
FAMILI	Amplitude	Rep. Rate	t _W	t _R	t _F
74LVT	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns

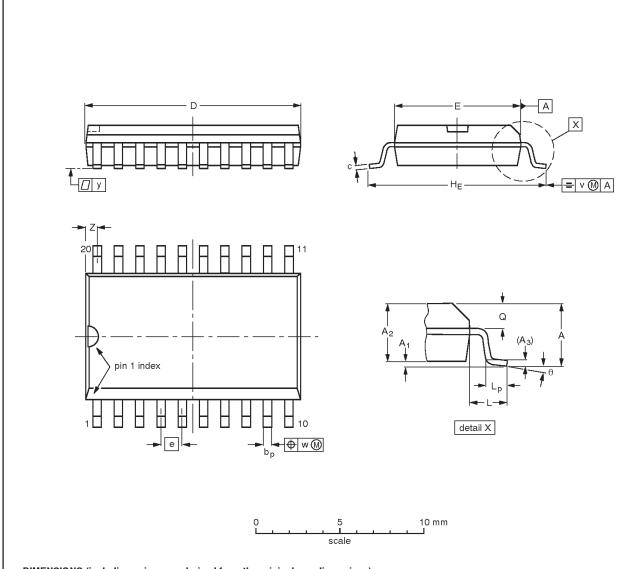
SV00092

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SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	Α1	A ₂	A ₃	bp	O	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	٧	w	у	z ⁽¹⁾	θ
mm	2.65	0.30 0.10	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.10	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.050	0.42 0.39	0.055	0.043 0.016		0.01	0.01	0.004	0.035 0.016	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE		
SOT163-1	075E04	MS-013AC			-92-11-17 95-01-24		

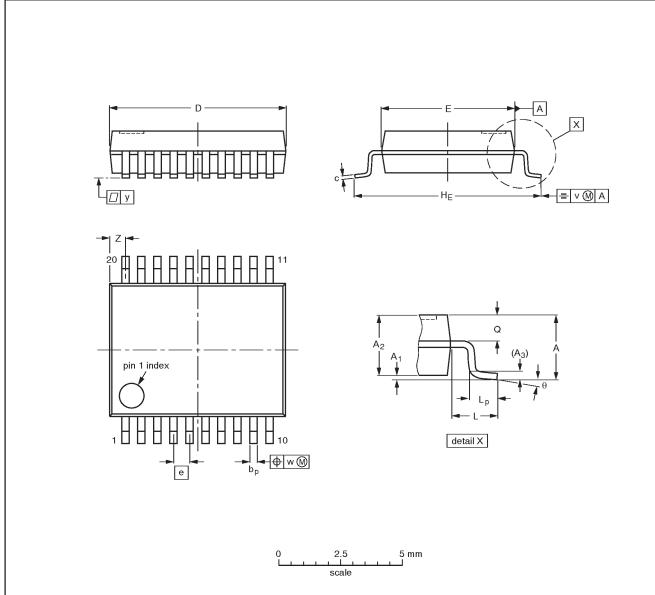
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SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A ₂	A ₃	bр	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	7.4 7.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.9 0.5	8° 0°

Note

1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

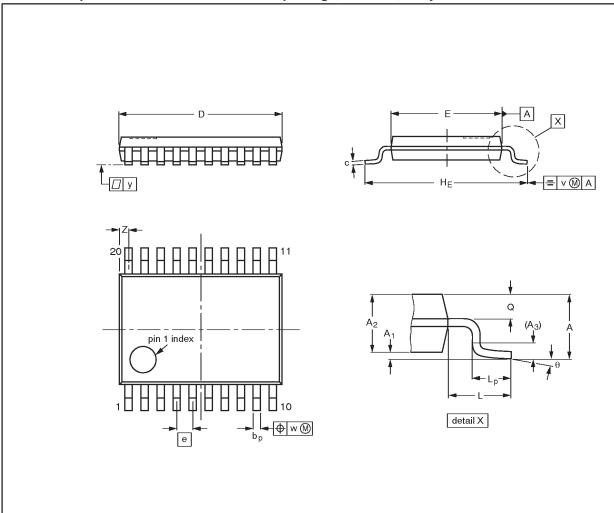
OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT339-1		MO-150AE			93-09-08 95-02-04

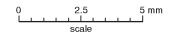
3.3V Octal transceiver with direction pin; inverting (3-State)

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TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1





DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A ₂	A ₃	рb	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT360-1		MO-153AC			-93-06-16 95-02-04

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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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^[1] Please consult the most recently issued datasheet before initiating or completing a design.

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